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" IMPROVEMENTS IN OR RELATING TO THE PRODUCTION OF COPPLER FOILS SUITABLE FOR PRINTED CIRCUITS"

Council of Scientific and Industrial Research, Rafi Marg, New Delhi-1, India, an Indian registered body incorporated under the registration of Societies Act (Act XXI of 1860).

The following specification describes the nature of this invention :-

PRICE: TWO RUPEES

14105 This is an invention by BALKUNJE ANANTHA SHENOI, Scientist, Central Electrochemical Research Institute, Karaikudi, Tamil Nadu, India and is an Indian National.

This invention relates to improvements in or relating to the production of copper foils suitable for printed circuits.

Hitherto it has been proposed to produce copper foils for printed circuits, and similar components by a process of m electrodeposition from a solution containing mainly copper sulphate and sulphuric acid with certain addition agents like phenol sulphonic acid, citric acid or gelatin so that the produced copper foil will have the required mechanical properties. The current density employed is of the order of 15 A/dm².

This is open to the objection that in spite of the addition agents, the current density employed is low as a result of which continuous foil formation will not be feasible.

The object of this invention is to obviate these disadvantages by making certain addition of inorganic salts which will eliminate the above defect and facilitate application of high current densities of the order of 20-50 A/dm^2 for agitated solutions.

To these ends, the invention broadly consists in adding alkali metal salts of nitrates, perchlorates and flueborates or respective acids singly or in combination to the above mentioned copper sulphate sulphuric acid bath. The concentration of such salts ranges between 5 and 12.5 g/l.

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The following typical ecamples are given to illustrate the invention :

EXAMPLE 1

The electroforming of copper foil was carried out using the following bath composition adopting the usual procedure:

Copper sulphate:	220 g/1
Sulphuric acid:	60 g/1
Aluminuim sulphate:	14 g/1
Cl ⁻ ion	30 mg/1
Potassium perchlorate	3 119/1
Current dinsity	27 A/dm^2
Temperature	40°C
Thickness of the foil	12.5 mil
Time	1 hour

The copper foil obtained from the above bath was free from pittings and perforations. The stress measurement of the foil indicated that the additions of potassium perchlorate does not have any influence on stress.

EXAMPLE 2

The following bath composition was used for electroforming of copper foil :

Copper sulphates	210 9/1
Sulphuric acid:	60 g/1
Hydrochloric acid:	0.05 cc/litre
Potassium perchlorate:	7 g/1
Temperature	36 ⁰ 0
Current density	32 A/dm^2
Thickness	15 mil

EXAMPLE 3

The electroforming of copper foil was carried out using the undermentioned bath:

Copper sulphate:	250 g/1
Sulphuric acid:	60 g/1
Phenol sulphonic acid:	1.2 g/1
Citric acid:	5.2 g/1
Potassium perchlorate:	8 g/1

Current density:	32 A/dm?
Plating time	1 hour
Temperature	45 [°] C
Thickness obtained	15 mil/hour

The copper foil obtained from the above bath was comparable with the foil obtained from the conventional bath with regard to stress.

EXAMPLE 4

The following bath composition was used for getting electroformed copper foil:

Copper sulphate:	240 g/1
Sulphuric acid	75 a/1
Casein	0.3 g/1
Gelatin or animal glue	0.03 g/1
Potassium perchlorate	3 9/1
Current density	43 h/dm^2
Temperature	45 ⁰ C
Plating time	2 hours
Thickness of the copper foil	40 mil

EXAMPLE 5

Electroforming of copper to obtain foil was carried out using the undermentioned bath:

Copper sulphate:	220 9/1
Sulphuric acid:	60 g/1
Aluminium sulohate	14 0/1
Chloride ion	30 mg/1
Sodium nitrate	5 g/1
Temperature	40 ⁰ C
Plating time) hour
Current density	27 A/dm^2
Thickness of the foil	12.5 mil

EXAMPLE 6

The following copper plating bath was used to electroform copper foil:

C1	Copper sulohate:	210 g/1
	Sulphuric acid Potassium nitrate£	60 q/1 12 q/1
	Hydrochloric acid	0.05 cc/1
	Temperature	40 ⁹ c
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Current density:	37.5 A/dm²
Plating time:	1 hour
Thickness of the foil	17.5 mil

EXAMPLE 7

Electroforming of cooper foil was carried out using the bath composition given in Example 3 with the addition of potassium nitrate 15 g/l instead of potassium perchlorate for a duration of one hour at 45°C at a current density of 32.5 A/dm². The copper foil obtained was 15 mil thick.

EXAMPLE 8

The electoforming of copper foil was carried out using the bath described in Example 4 wigh the addition of sodium nitrate 5 g/l instead of potassium perchlorate for a duration of one hour at 43 A/dm² current density. The thickness of the copper foil obtained was 20 mil.

EXAMPLE 9

Electroforming of copper foil was carried out using the bath described in Example 1 using potassium fluoborate 100 g/l instead of potassium perchlorate. Duration and current density of the plating was same as in Example 1.

Smooth uniform copper foil of thickness 12.5 mil was obtained.

EXAMPLE 10

Electroforming of copper foil was carried out using the bath composition described in Example 1 using a mixture of nitric acid (5cc/1) and potassium perchlorate (3 g/1), instead of potassium perchlorate above under identical condition as in Example 1. Good uniform copper foil was obtained with a thickness of 12.5 mil.

In the same experiment, instead of nitric acid, fluoboric acid (5 cc/1) of the plating bath with potassium perchlorate (3 g/1) was used under same condition and copper foil of thickness 12.5 mil was obtained.

EXAMPLE 11

Electroforming of copper foil was carried out using the composition given in Example 1 using fluoboric acid 5 cc/1 of the plating bath with potassium hitrate 5 gm per litre. Electroforming was carried out for one hour at 21.5 A/dm^2 current density and the thickness of the foil was found to be 10 mil.

The following are among the main advantages of the invention:

- High current densities of the order of 20 to 50 A/dm²
 can be employed. This facilitates fast production when
 continuous foil formation is contemplated.
- 2. The crystal orientation of the copper has been found to be lamullar which facilitates uniform etching during preparation of the printed circuits using this foil.

Dated this 21st day of February, 1974.

sd/-Asst. Patents Officer, Council of Scientific & Industrial Research.

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THE PATENTS ACT 1970

COMPLETE SPECIFICATION

SECTION 10

"Improvements in or relating to the production of copper foils suitable for printed circuits."

Council of Scientific & Industrial Research, Rafi Marg, New Delhi-1, India, an Indian registered body incorporated under the registration of Societies Act (Act XXI of 1860)

The following specification praticularly describes and ascertains the nature of this invention and the manner in which it is to be performed.

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This is an invention by BALKUNJE ANANTHA CHENOI, Scientist, Centra Electrochemical Research Institute, Karaikudi-6, Tamil Nadu, India, and he is an Indian Citizen.

This invention relates to improvements in or relating to the production of copper foils suitable for printed circuits.

Hitherto it has been proposed to produce copper foils for orinted circuits, and similar components by a process of electrodeposition from a solution containing manly copper sulphate and sulphuric acid with certain addition agents like phenol sulphonic acid, citric acid or gelatin so that the produced copper foil will have the required mechanical properties. The current density employed is of the order of 15 A/dm².

This is open to objection that notwithstanding the addition agents, the current density employed is low as a result of which continuous foil formation will not be feasible.

The main object of the present invention is to obviate these disadvantages by making certain addition of inorganic salts which will eliminate the above defect and facilitate the the application of high current densities of the order of 20-50 A/dm^2 for againsted solutions.

The main finding underlying the invention consists of the process of electroforming of copper on a stainless steel

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mandrel from an aqueous electrolysing bath comprising the 'following:

a)	Copper	sulphate	150 -	• 300 g	1/1	L
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- b) Sulphuric acid 40 150 g/1
- c) and alkali metal salts of initrates, perchlorates and fluoborates or respective acids singly or in combinations as inorganic additions agent ... 1 - 15 g/1

and electroforming at current densities of the order of 20-50 A/dm^2 at temps of 30-50°C to produce pore free copper foil.

The new result flowing from the new finding is that the use of inorganic addition: agent enable the production of sore free copper foil at high current densities of the order of $20-50 \text{ } \text{ A/dm}^2$ suitable for printed circuits.

The present invention consists of a process for electroforming of copper foils suitable for printed circuits which comprises the steps of mechanical polishing and buffing of the stainless steel mandrel degreasing with trichloroethylene, alkaline cleaning in 5% sodium phosphate solution, passivating in a solution of 1% chromic acid, and subsequently the said mandrel is used as cathode in the aqueous electroforming bath containing 150-300 g/1 copper sulphate, 40-150 g/1 subphuric acid alongwith 1-15 g/1 of alkali metal salts of nitrates, perchlorates and fluoborates or respective acids singly or in combination as addition agent where in the said addition agent enables the production of pore free copper foils at relatively higher current densities of the order of 20-50 A/dm² at temps. of 30-50°C. The said electroformed foil is ultimately separated from the mandrel and used in the production of printed circuits.

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The flow sheet of the process is given in fig. 1,

The following typical examples are given to illustrate the invention and not to limit the scope of the invention.

EXAMPLE -1

A stainless steel plate of the size 25 cm x 25 cm. was mechanically polished and buffed, degressed with trichloro ethylene, cathodically cleaned in 5% sodium phosphate solution and passivated in 1% chromic acid for about three minutes before taking to the following electroforming bath:

Copper sulphate	220 g/1
Sulphuric acid:	6 0 g/1
Aluminium sulphate:	14 9/1
Cl ⁻ ion	30 mg/1
Potassium perchlorates	3 g/1
Current density:	27 Adm ²
Temperature:	40°C
Time:	1 hour
Thickness of the foil:	12.5 mil
Current efficiency:	96%

The cooper foil obtained from the above bath was free from pittings and perforations. The stress measurement of the foil indicated that the addition of potassium perchlorate does not have any influence on stress.

EXAMPLE - 2

The stainless steel plate was treated as in Example 1 and the following bath composition was used for electroforming of copper foil:

Copper sulphate:	200 g/1
Sulphuric acid:	150 g/1
Hydrochloric acid:	0.05 cc/litre
Potassium perchlorate:	1 g/1
Temperature:	36 ⁰ C
Current density:	32 A/dm ²
Thickness:	15 mil
Current efficiency:	96 ,5%

EXAMPLE -3

The electroforming of copper foil was carried out using the undermentioned bath:

Copper sulphate:	300 q/1
Sulphuric acid:	60 g/1
Phenol sulphonic acid:	1.2 9/1
Citric acid:	5.2 9/1
Potassium perchlorate:	5 g/1
Current density:	32 A/dm^2
Plating time:	1 hour
Temperature:	45°C
Thickness obtained:	15 mil/hour
Current efficiency:	97%

The copper foil obtained from the above bath was comparable with the foil obtained from the conventional bath with regerd to stress.

EXAMPLE-4

The following bath composition was used for getting electroformed copper foil:

Copper sulphate:	240 g/1	
Sulphuric acid:	40 g∦1	
Casein:	0.3 9/1	
Gelatin or animal glue:	0.03 g/1	
Potassium perchlorate:	3 9/1	
Current density:	43 A/dm^2	
Temperature	45 ⁰ C	
Plating time:	2 hours	
Thickness of the copper foil: 40 mil		
Current efficiency:	95%	

EXAMPLE -5

Electroforming of cooper to obtain foil was carried out using the undermentioned bath:

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Copper sulphate:	220 0/1
Sulphuric Acid:	100 g/1
Aluminium sulphate:	14 q/1
Chloride ion:	30 mg/1
Sodium nitrate:	2.5 g/1
Temoerature:	40°C
Plating time:	1 hour
Current density:	27 A/dm ²
Thickness of the foil:	12.5 mil
Current efficiency:	94%

EXAMPLE -6

The following copper plating bath was used to electroform . copper foil:

Copper sulphate:	210 g/1
Sulphuric acid:	60 g/1
Potassium hitrate:	12.9/lcc/2
Hydrochloric acid:	0.05 cc/1
Temperature:	40 ⁰ C
Current density:	37.5 A/dm^2
Plating time:	1 hour
Thickness of the foil:	17.5 mil
Current efficiency:	95.5%

EXAMPLE-7

Electroforming of copper foil was carried out using the bath composition given in Example 3 with the addition of potassium nitrate (15 g/l) instead of potassium perchlorate for a duration of one hour at 45° C at a current density of 32.5 A/dm². The copper foil obtained was 15 mil thick. The current efficiency of the bath was 97%.

EXAMPLE-8

The electroforming of copper foil was carried out using the bath described in Example 4 with the addition of sodium nitrate (5 g/l) insteadof potassium perchlorate for a durattion of one hour at 5Q A/dm² current density. The thickness of the copper foil obtained was 25 mil and the current efficiency was 95%.

EXXMPLE-9

Electroforming of copper foil was carried out using the bath described in Example 1 using potassium fluoborate (10.0 g/l) instead of potassium perchlorate. Duration and current density of the plating was same as in Example 1. Smooth uniform copper foil of thickness (12.5 mil)was obtained and the current efficiency was 94%

EXAMPLE-10

Electroforming of copper foil was carried out using the bath composition described in Example 1 using a mixture of nitric acid (5 cc/1) and potassium perchlorate (3 g/1), instead of potassium perchlorate above under identical condition as in Example 1. Good uniform copper foil was obtained with a thickness of 12.5 mil and the current efficiency was found to be 96%.

In the same experiment, instead of mitric acid, fluor boric acid (5cc/1) of the plating bath with potassium perchlorate (3 g/1) was used under same condition and a copper foil of thickness 12.5 mil was obtained. The current efficiency of the bath was 95%.

EXAMPLE -11

Electroforming of copper foil was carried out using the composition given in Example 1 using fluoboric acid (5 cc/l) of the plating bath with potassium mitrate (5 g/l). Electromforming was carried out for one hour at 21.5 Δ/dm^2 current density and the thickness of the foil was found to be 10mil. The current efficiency of the bath was 94%.

In all the above Example, the electroformed copper foil was found to possess a lamellar structure. The replenishment of the bath was made by visualising the Ourface condition of the foil. This could also be done by the usual analytical methods.

The following are among the main advantages of the inventions 1. High current densities of the order of 20 to 50 A/dm² can be employed. This facilitates fast production when continuous foil formation is contemplated.

2. The crystal orientation of the copper has been found to be lamellar which facilitates uniform etching during preparation of the printed circuits using this foil.

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I CLAIM

A process for electroforming of copper foils suitable for 1. printed circuits which comprises the steps of mechanical polishing and buffing of the stainless steel mandrel. degreasing with trichloroethylene, alkaline cleaning in 5% sodium phosphate solution, passivating in a solution of 1% chromic acid and subsequently the said mandrel is used as cathode in the aqueous electroforming bath containing 150-300 g/1 copper sulphate, 40-150 g/1 sulphuric acid alongwith 1-15 g/1 alkali metal salts of nitrates, perchlorates and fluoborates of respective acids singly or in combination as addition agents wherein the said addition agents enables the production of pore free copper foils at relatively higher current densities of the order of 20-50 A/dm² at temps. of 30-50°C, the said electroformed foil is ultimately separated from the mandrel and used in the production of printed circuits.

Bated this 20th day of February 1975.

sd/-(R. BHASKAR PAI) PATENIS OFFICER COUNCIL OF SCIENTIFIC & INDUSTRIAL RESEARCH.

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